

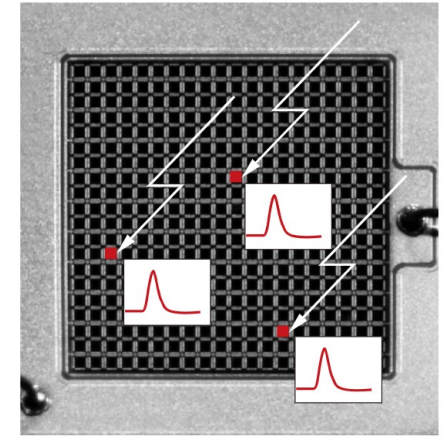
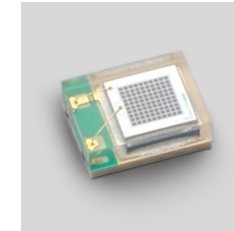
Study on SiPM saturation

Tatsuki Murata, University of Tokyo, on behalf of the Sc-ECAL group
Annual ILC-detector meeting 9 Mar. 2022

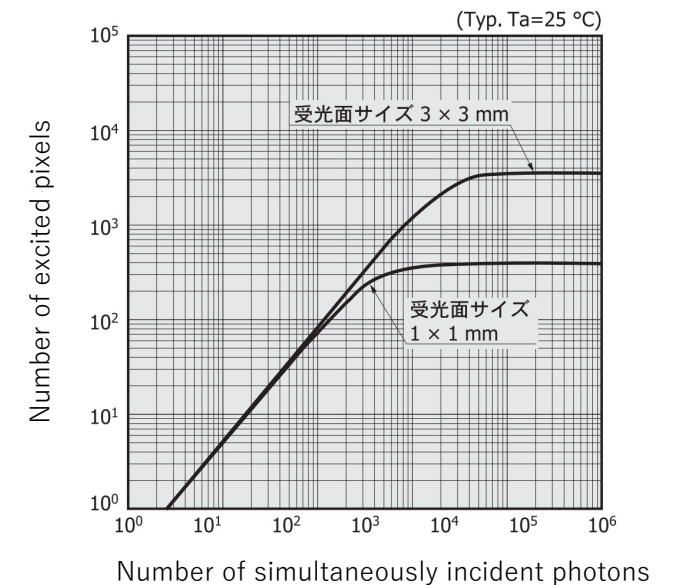
SiPM Saturation

- SiPM signal saturates for many photons due to limited number of pixels.
 - Pile-up hits in small and dense EM shower into ScECAL
 - Proper correction for SiPM saturation is crucial for ECAL
- This saturation curve is affected by
 - scintillation emission time constant (a few ns)
 - SiPM recovery time (a few ns)
- We propose a new method to measure SiPM saturation curve with scintillation light excited by injecting UV light pulse.

[Figure 1-2] Image of SiPM's photon counting



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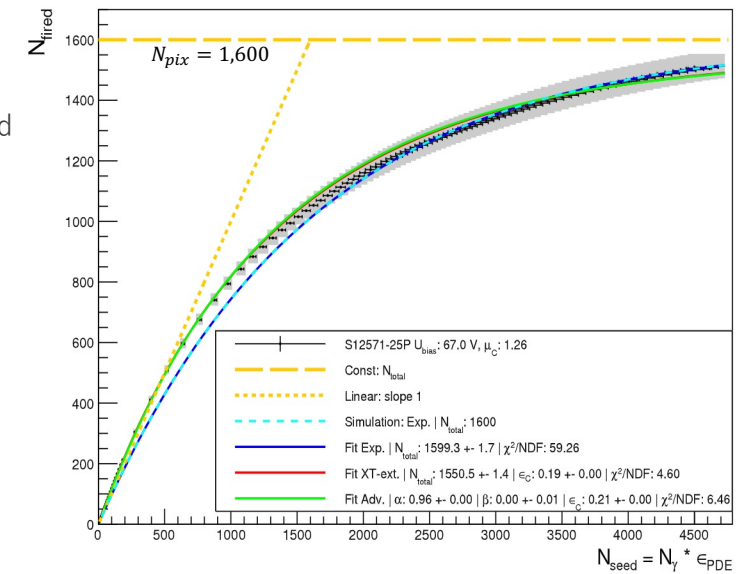
Hamamatsu Photonics K.K.
Opto-semiconductor Handbook

Experimental principle

N_{seed} : number of photoelectrons when assuming no saturation

N_{detected} : number of photons MPPC detected

- Saturation is usually studied by injecting fast visible-light pulse (~ 400 nm) directly to SiPM.
- Here, the measurement can be done by injecting UV light to the scintillator-SiPM system
 - **Excite scintillator by UV light**
 - **Scintillation light intensity is controlled by the UV light intensity**
 - **Effect of scintillation emission time constant is included.**
 - **Measured saturation curve can be used directly for the saturation correction.**

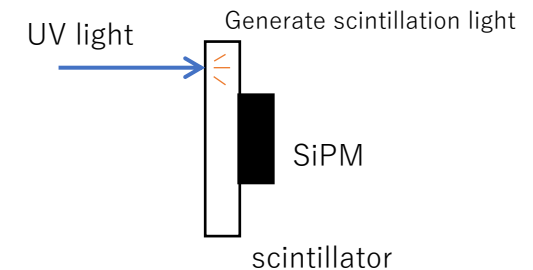


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Conventional method

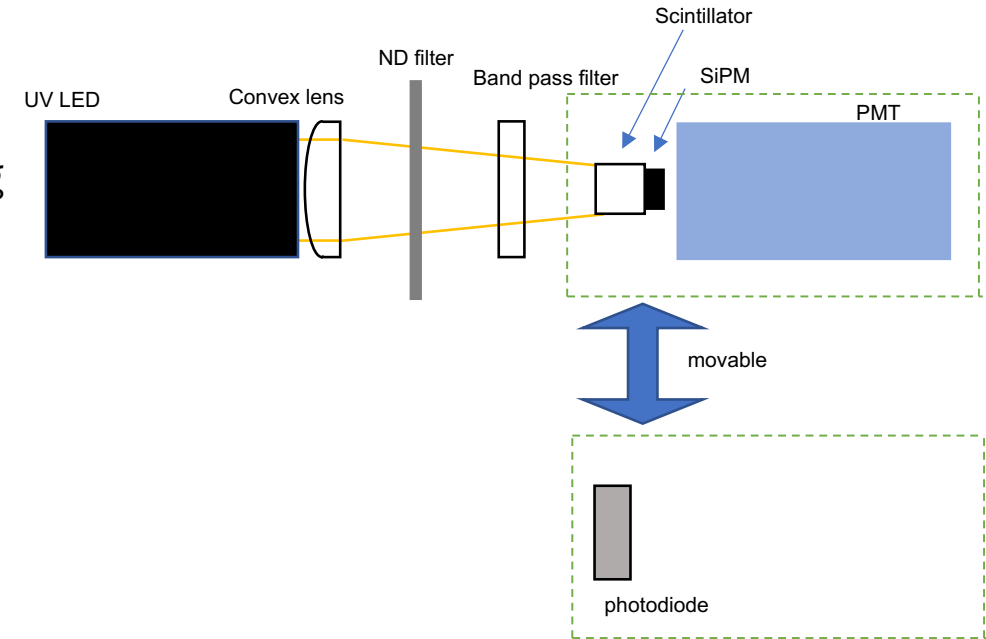


New method

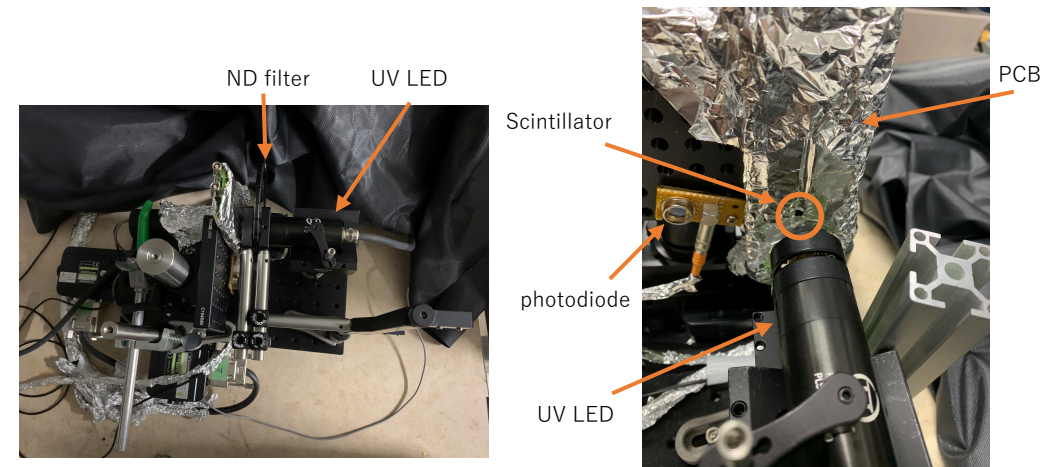


Saturation measurement -set up-

- UV light pulse irradiate scintillator and photodiode by using moving stage
 - Photodiode monitors the intensity of UV light
 - The intensity is controlled using ND filter
 - SiPM detects scintillation light to observe saturation
 - PMT also detects scintillation light
 - PMT has much wider range
 - To check the relation between the intensity of the UV light and the scintillation light
- SiPM : Hamamatsu MPPC S12571-025P
- Scintillator : EJ-200
- Light source : PicoQuant PLS series
 - Measured also with visible light pulse for comparison

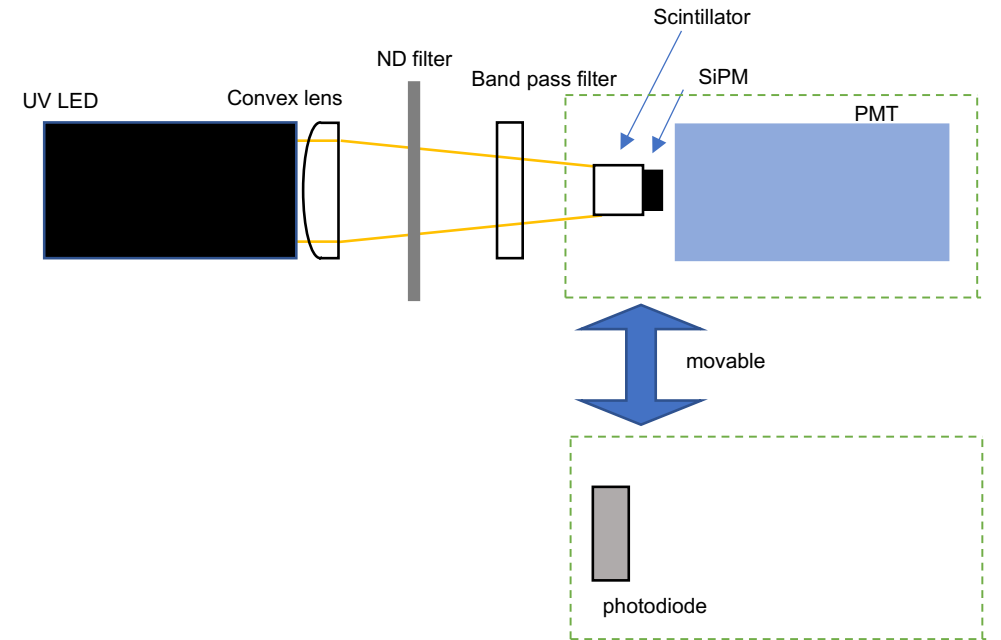


| | | | | | | |
|------------------|---------------------|-----------------------------|--------|-------------------------|-----------|-----------|
| S12571-025P | | EJ-200 | | | PLS 255 | PLS 500 |
| Effective area | 1×1 mm ² | Attenuation length | 380 cm | Wavelength [nm] | 255 (±10) | 485 (±10) |
| Pixel pitch | 25 μm | Maximum wavelength emission | 425 nm | Pulse width (FWHM) [ps] | ~400 | ~800 |
| Number of pixels | 1,600 | rise time | 0.9 ns | | | |
| | | decay time | 2.1 ns | | | |



Saturation measurement -DAQ-

- Signal readout
 - SiPM signal is mainly measured in current at source meter.
 - To avoid the saturation of electronics
 - Also measured at digitizer at low UV intensity
 - To calibrate SiPM current and photoelectrons (p.e.)
 - Photodiode is measured in current at source meter
 - PMT is measured in photoelectrons at waveform digitizer



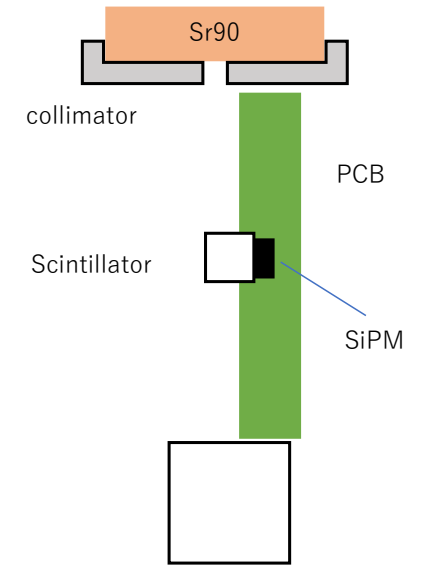
| Detector | Signal Readout |
|------------|----------------|
| | |
| SiPM | current |
| | photoelectron |
| Photodiode | current |
| PMT | Photoelectron |

Excitation of scintillator

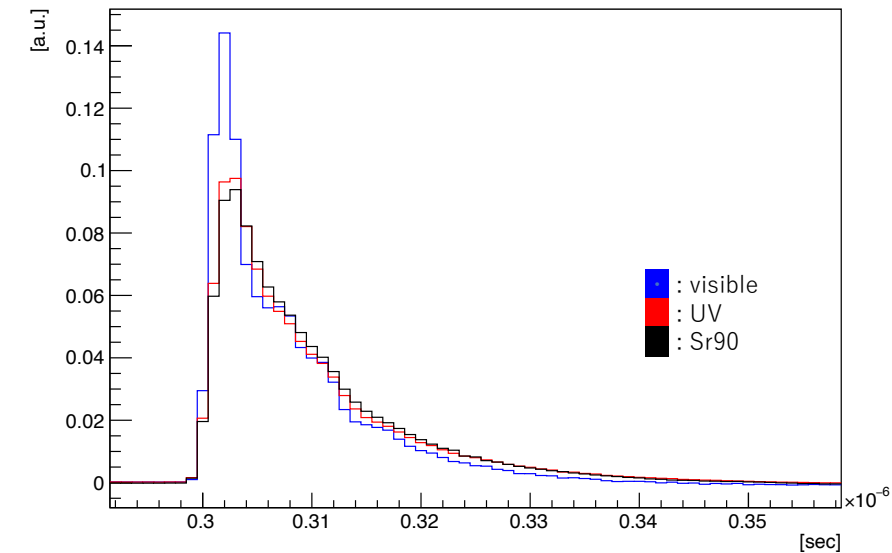
- Compared waveforms of SiPM signals of UV light, visible light, Sr90

- Visible light : sharp peak
- UV light, Sr90 : gentle peak

→ Using UV light, photons are injecting SiPM for a long time compared to visible light

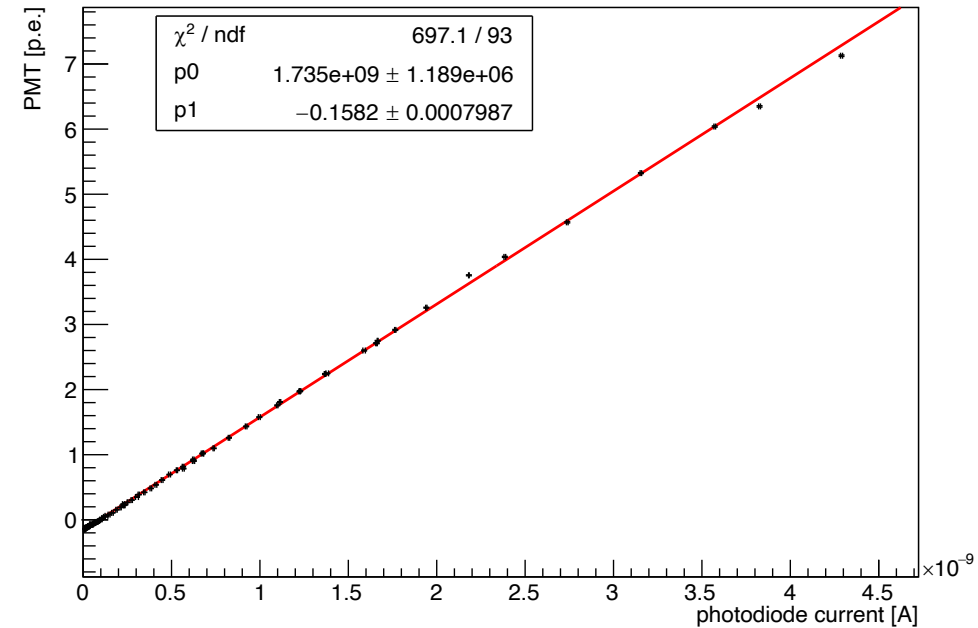


Trigger counter ($5 \times 5 \times 5 \text{ mm}^3$ scintillator + SiPM)



Relation between UV and scintillation light

- PMT is placed behind the SiPM to calibrate the relation between the intensity of UV light and generated scintillation light
- Linear relation is observed in wide range
 - The number of incident scintillation photons can be estimated from the intensity of UV light

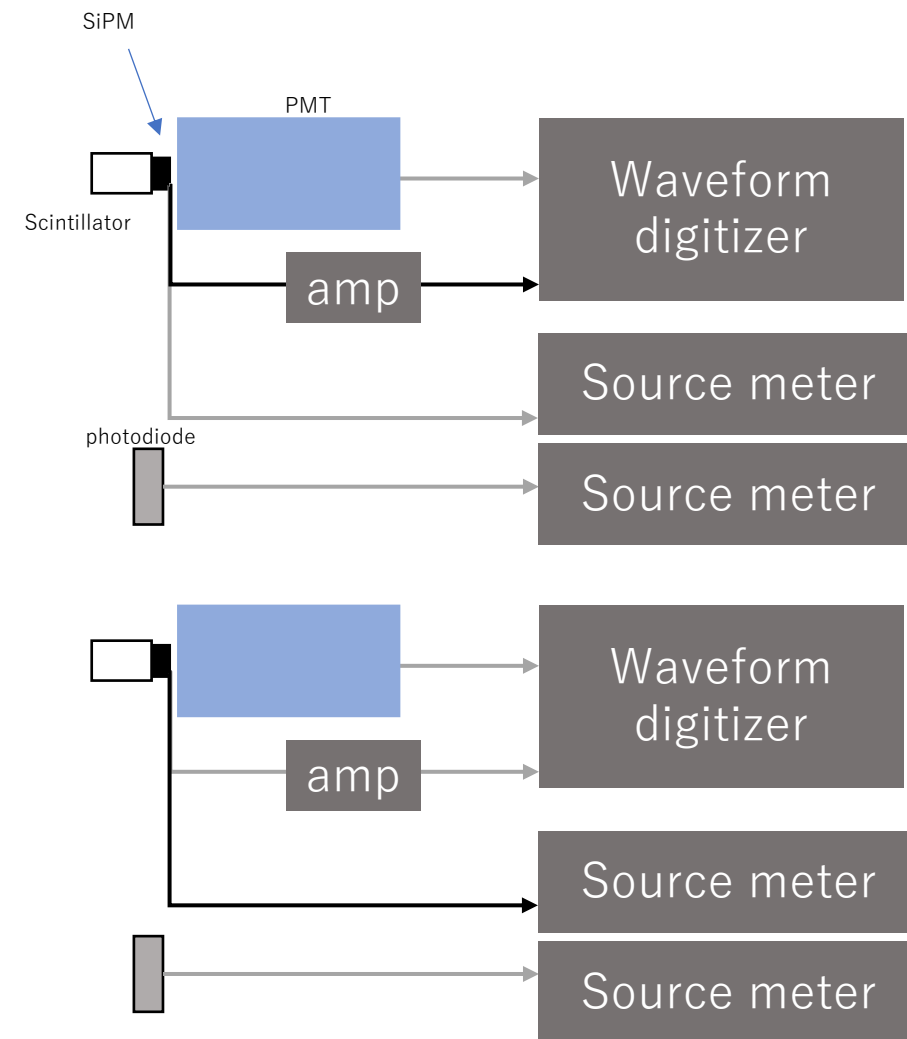
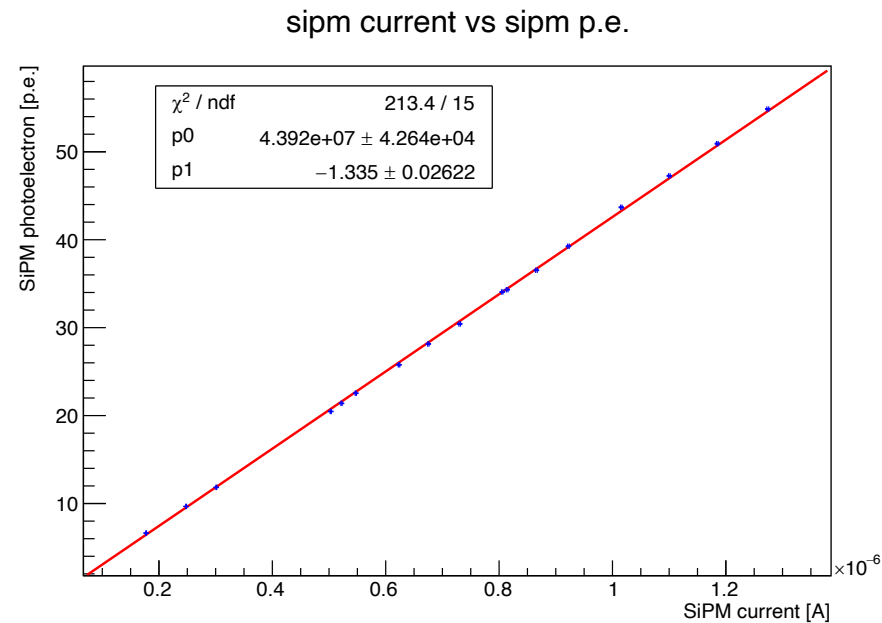


Analysis N_{detected}

N_{seed} : number of photoelectrons when assuming no saturation

N_{detected} : number of photons MPPC detected

- SiPM signal is measured by two ways
 - Current at source meter
 - Photoelectron at digitizer
- N_{detected} calibration
 - Convert SiPM current [mA] into photoelectrons [p.e.] using relation at low LED intensity.

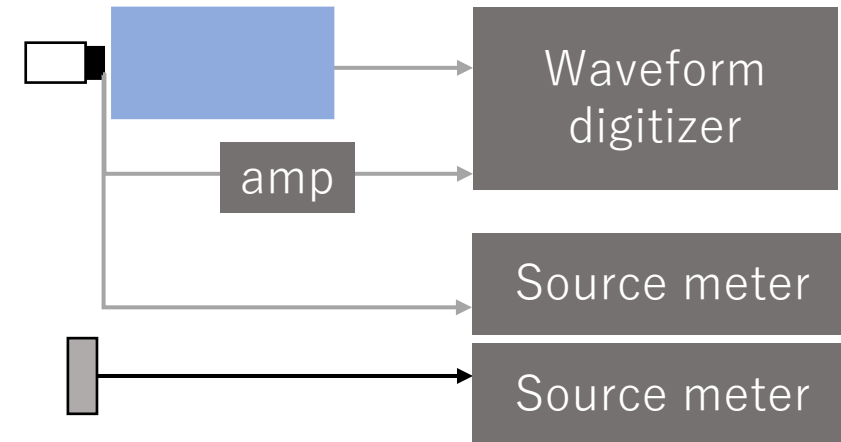
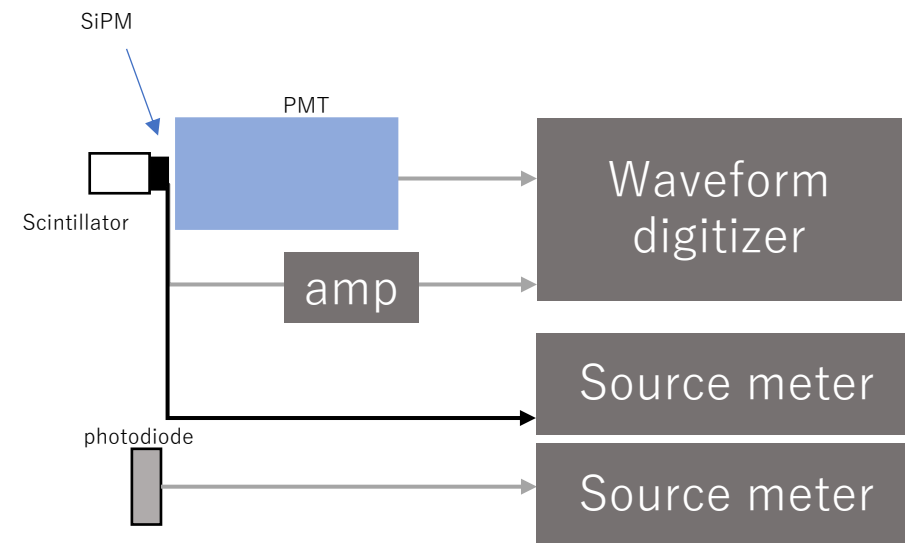
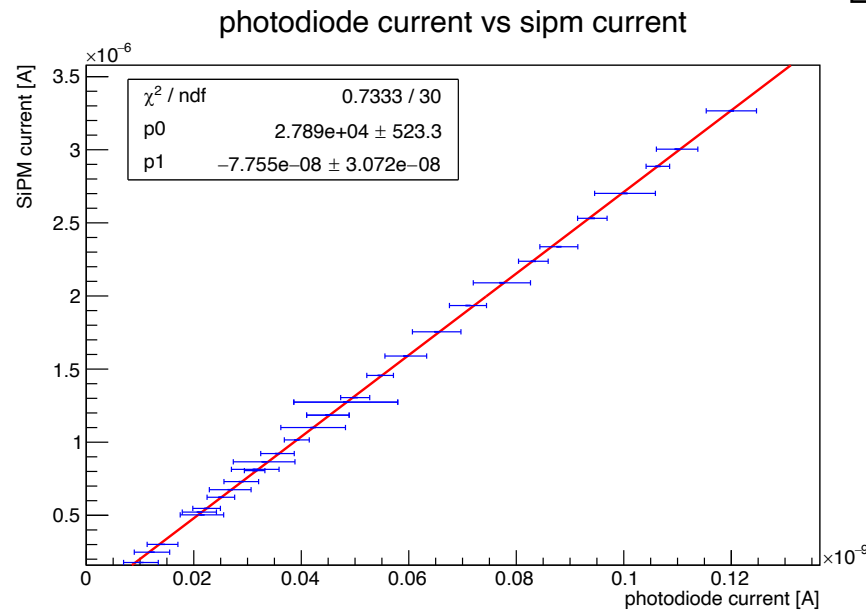
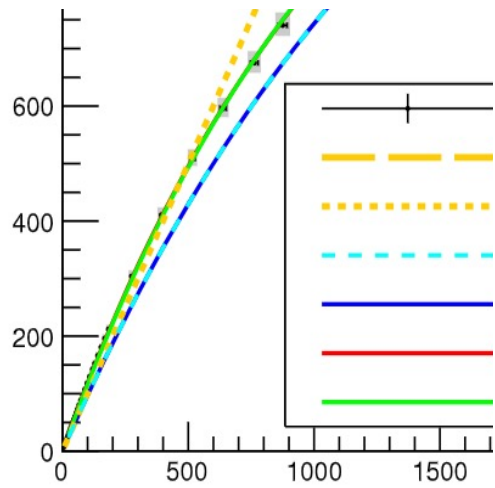


Analysis N_{seed}

- Source meter measures SiPM and photodiode current
- Photodiode monitors the intensity of UV
 - To estimate N_{seed}
- N_{seed} calibration
 - Relation between photodiode current and SiPM output at low LED intensity.

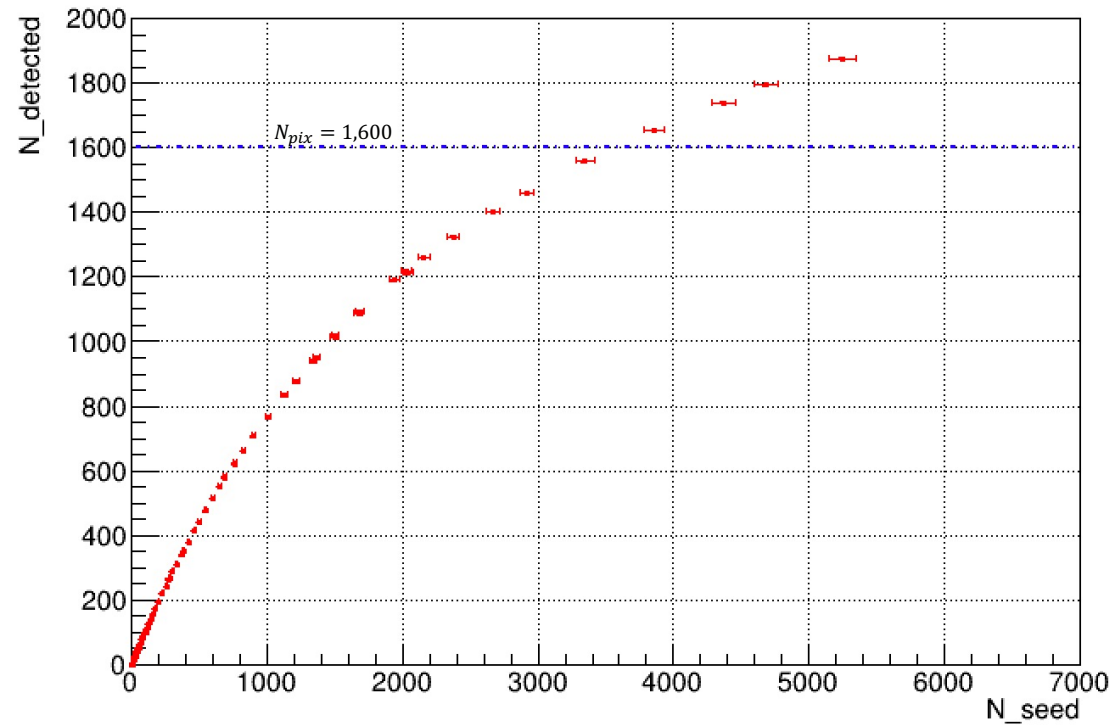
N_{seed} : number of photoelectrons when assuming no saturation

$N_{detected}$: number of photons MPPC detected



Saturation curve

- Saturation curve is obtained after the N_{detected} and N_{seed} calibration
- Over saturation and a large recovery of SiPM is observed
 - Saturation is relieved for UV curve



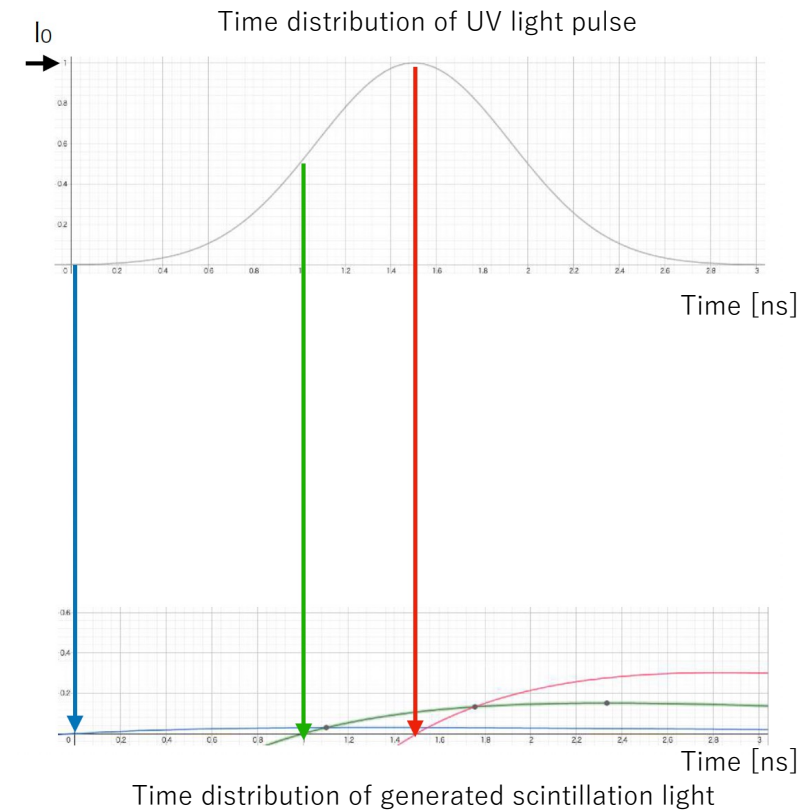
Saturation model

- Developed new saturation model by calculation
 - Prepare time distribution of incident photon
 - For UV, convolution of UV light pulse and scintillation emission
 - Divide time by the step width and for each time i , calculate incident photons $N_{int}(i)$, detected photons $N_{det}(i)$ and $N_{seed}(i)$
 - Sum up $N_{det}(i)$ and $N_{seed}(i)$ for all time
- Increase the intensity of light pulse and repeat the calculation

- For each time i ,

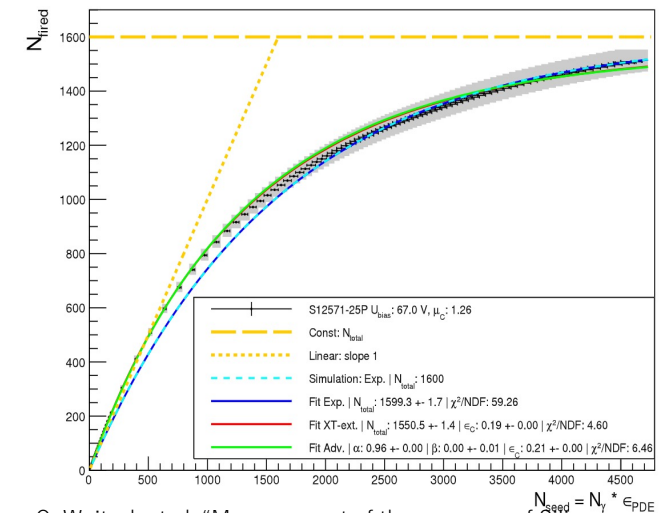
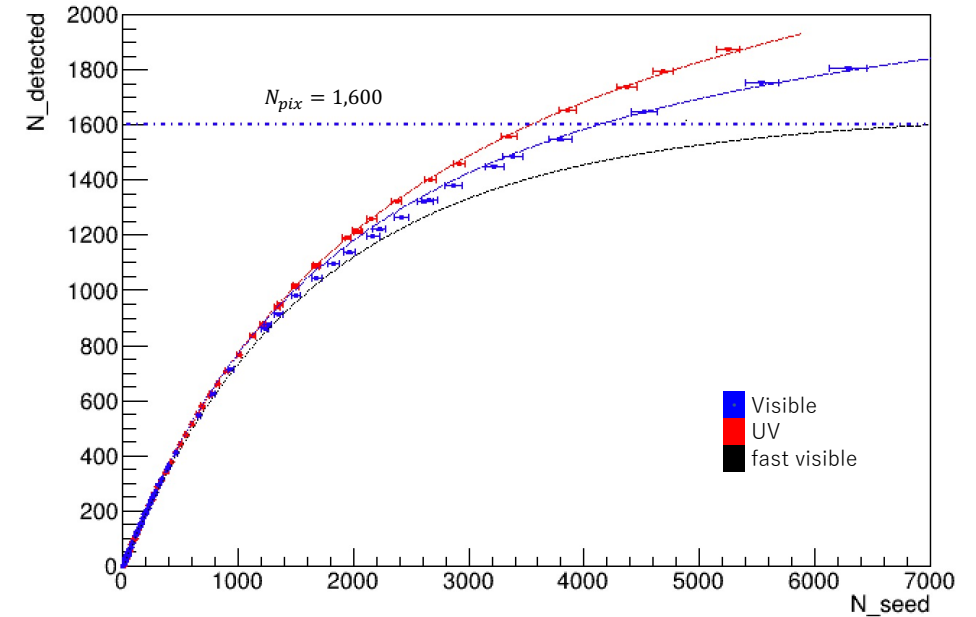
- $$N_{seed}(i) = \frac{N_{int}(i)}{N_{pix}} * \sum_j^i (N_j * PDE(i - j))$$
- $$N_{CT}(i) = N_{seed}(i) * (P_{CT} + P_{CT}^2 + \dots)$$
- $$N_{det}(i) = N_{seed}(i) + \frac{N_{CT}(i)}{N_{pix}} * \sum_j^i (N_j * PDE(i - j))$$
- $$N_{AP}(i) = \sum_j^i (N_j * AP(i - j))$$
- $$N_{seed}(i) = N_{seed}(i) - N_{AP}(i)$$

N_j : number of pixels the last photon enters at time j
 $PDE(i - j)$: decrease of PDE caused by recovery time
 N_{CT} : increased number of photon due to crosstalk
 N_{AP} : decreased number of N_{seed} due to after-pulse
 $AP(i - j)$: time distribution of after-pulse



Comparison of measured and model curve

- Measured curve and model curve is compared.
 - Model curve well describes measured curve.
- Visible light had longer pulse ($\sim 2\text{ns}$) than the conventional saturation measurement ($\sim 100\text{ps}$)
 - Calculated conventional saturation curve (black curve)
 - consistent with the conventional curve
- Curve with UV light observed over saturation and large pixel recovery comparing to conventional measurement
 - Due to scintillation emission time constant



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Summary and prospect

- We propose a new method to measure SiPM saturation with scintillation light
 - Scintillation light is excited by injecting UV light pulse
- Found a linear relation between the scintillation light and the intensity of UV light
- Measured saturation curve
 - A large recovery of the SiPM saturation is observed
- Developed new saturation model including the effect of crosstalk, after-pulse, and pixel recovery
 - Confirmed the new model well describes the measured saturation curve.

Back ups